

**B.E. ELECTRONICS AND TELE-COMMUNICATION ENGINEERING
SECOND YEAR SECOND SEMESTER EXAM, 2023**

ANALOG CIRCUITS- II

Time: Three hours

Full Marks: 100

Module I (30)

1. Explain the following (**Any ten**) 3×10=30
- Advantages of multistage over single stage amplifiers.
 - Advantages of capacitive coupling over other coupling methods.
 - The input stage of a voltage amplifier is better with MOSFET than BJT.
 - Importance of distortion analysis in large signal amplifier.
 - Efficiency of class B power amplifier is higher than class A power amplifier.
 - Class-C Amplifiers cannot be used in audio frequency range.
 - Q-factor of tuned amplifier is very high.
 - Advantages of negative feedback.
 - Barkhausen Criterion for oscillations.
 - The hysteresis in Schmitt-trigger circuit.
 - Advantages of crystal oscillator over RC and LC oscillators.
 - Role of the 3rd capacitor in Clapp oscillator circuit.
 - Lock range and capture range of PLL.

Module II Any three (30)

2. a) Using small signal equivalent circuit calculate the midband-gain and input impedance without considering the effect of biasing resistances of a Cascode amplifier. Given that $I_C=1$ mA, $\beta=150$ (both transistors), $R_C||R_L=1k\Omega$. [5+5]
- b) Draw and compare frequency response characteristics of R-C coupled multistage CC-CE and CE-CE amplifier for all regions of operation. [5]
3. a) Compute 2nd order harmonic distortion of a class A power amplifier. Given that zero signal current $I_{CQ}=20$ mA, DC current after the application of the input signal is 25 mA. Peak-to-peak output current is 30 mA. [5]
- b) The class-A power amplifier is biased at $V_{CE}=12$ V. $\beta=100$, $V_{CC}=24V$, $R_C=50\Omega$. Load, $R_L=50 \Omega$, is capacitive coupled. Calculate the maximum power conversion efficiency of the amplifier. [5]
- c) Compare class-A and B power amplifiers with respect to different distortions present.

[Turn over

4. a) Sketch and illustrate the frequency response of a single-tuned and stagger-tuned amplifier. [10]
 b) Determine the bandwidth and quality factor of a 4-stage single-tuned amplifier. [5]
 Given that the quality factor of each identical stage is 4 and the resonant frequency is 100 kHz.
5. a) Calculate the voltage gain, input and output impedance of a voltage sampling and voltage mixing negative feedback circuit. Loop gain, Open loop voltage gain, input impedance and output impedance are 10, 100, 50k Ω and 1 k Ω respectively. [10]
 b) Identify the applications of a bistable and astable multivibrators. [5]

Module III (20)

6. (Any two)

- a) Develop the expression for output voltage if the transfer characteristic of MOSFET is given by a parabolic form ($v_{out} = A_0v_{in} + B_0v_{in}^2$), where A_0 and B_0 are constants and input is sinusoidal. 10 \times 2=20
 b) Derive the expression for the input resistance of the amplifier with current-sampling and voltage-mixing feedback topology.
 c) Develop the expression for frequency of oscillation of a Wein-Bridge oscillator.
 d) Develop the expression for the frequency of oscillation of a astable MV using BJTs.

Module IV (20)

7. (Any two)

- a) Design a class AB push-pull complementary symmetry power amplifier with the following specification. $I_{CQ}=40$ mA, $R_L=16$ Ω , $V_{CC}=20$ V. Choose practical values of components. Calculate the maximum efficiency. Assume diode drop=0V. 10 \times 2=20
 b) Design a Schmitt trigger using Op-Amp with a hysteresis width of 4 V.
 c) Construct a Pulse-width modulator with the help of monostable MV using 555 timer. Explain.
 d) Design a class-C tuned amplifier with oscillation frequency of 100 kHz and efficiency of 99.5%